

2SC535

Silicon NPN Epitaxial Planar

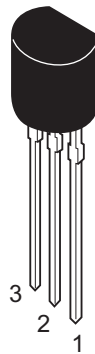
REJ03G0683-0200
 (Previous ADE-208-1047)
 Rev.2.00
 Aug.10.2005

Application

VHF amplifier, mixer, local oscillator

Outline

RENESAS Package code: PRSS0003DA-C
 (Package name: TO-92 (2))



- 1. Emitter
- 2. Collector
- 3. Base

Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	30	V
Collector to emitter voltage	V_{CEO}	20	V
Emitter to base voltage	V_{EBO}	4	V
Collector current	I_C	20	mA
Collector power dissipation	P_C	100	mW
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-55 to +150	°C

Electrical Characteristics

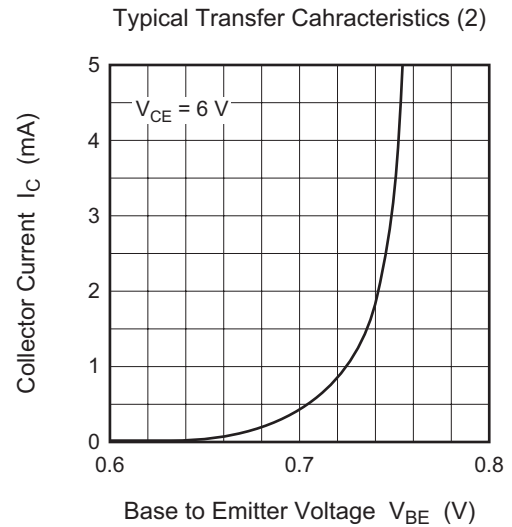
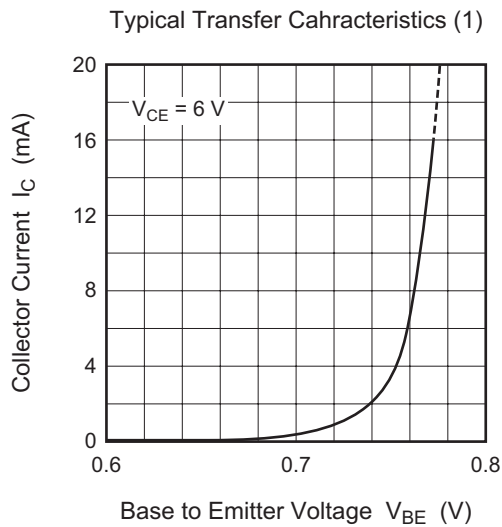
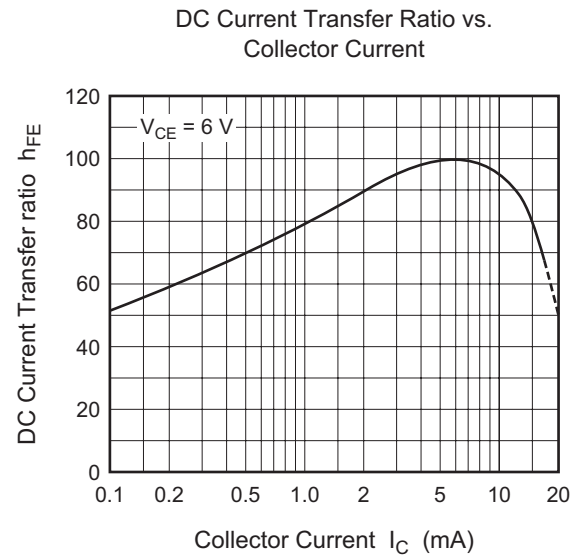
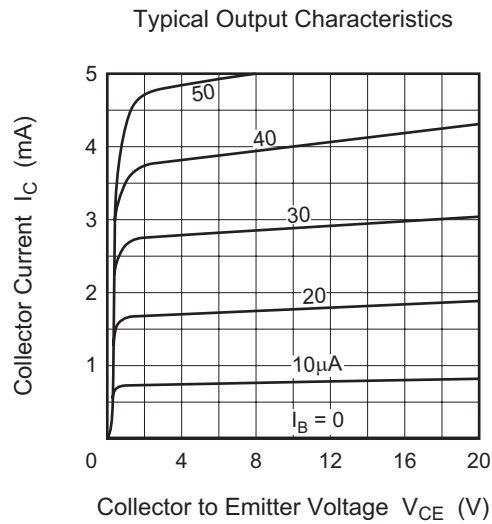
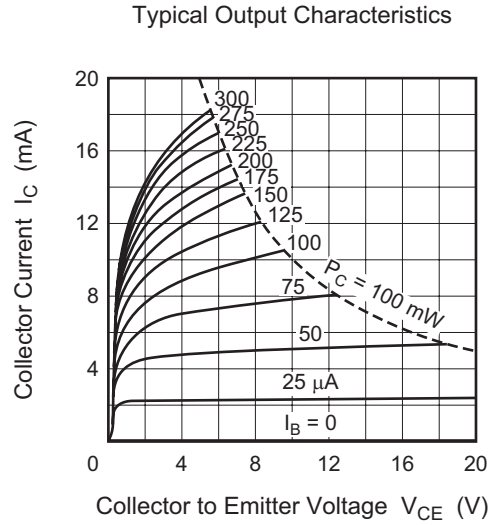
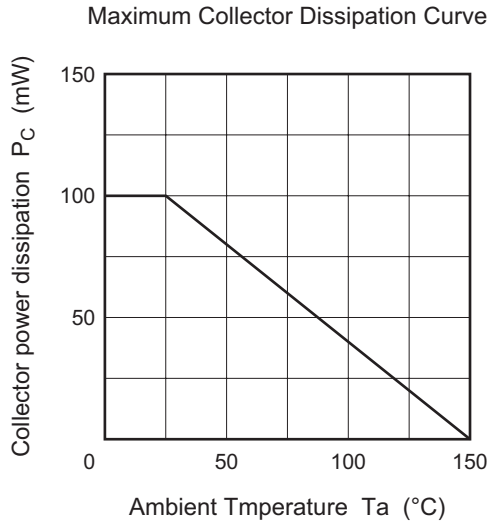
(Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	30	—	—	V	$I_C = 10 \mu A, I_E = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	20	—	—	V	$I_C = 1 \text{ mA}, R_{BE} = \infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	4	—	—	V	$I_E = 10 \mu A, I_C = 0$
Collector cutoff current	I_{CBO}	—	—	0.5	μA	$V_{CB} = 10 \text{ V}, I_E = 0$
DC current transfer ratio	h_{FE}^{*1}	60	—	200		$V_{CE} = 6 \text{ V}, I_C = 1 \text{ mA}$
Base to emitter voltage	V_{BE}	—	0.72	—	V	$V_{CE} = 6 \text{ V}, I_C = 1 \text{ mA}$
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	0.17	—	V	$I_C = 20 \text{ mA}, I_B = 4 \text{ mA}$
Gain bandwidth product	f_T	450	940	—	MHz	$V_{CE} = 6 \text{ V}, I_C = 5 \text{ mA}$
Collector output capacitance	C_{ob}	—	0.9	1.2	pF	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$
Power gain	PG	17	20	—	dB	$V_{CE} = 6 \text{ V}, I_C = 1 \text{ mA}, f = 100 \text{ MHz}$
Noise figure	NF	—	3.5	5.5	dB	$V_{CE} = 6 \text{ V}, I_C = 1 \text{ mA}, f = 100 \text{ MHz}, R_g = 50 \Omega$
Input admittance (typ)	y_{ie}	1.3 + j5.3			mS	$V_{CE} = 6 \text{ V}, I_C = 1 \text{ mA}, f = 100 \text{ MHz}$
Reverse transfer admittance (typ)	y_{re}	-0.078 - j0.41			mS	
Forward transfer admittance (typ)	y_{fe}	32 - j10			mS	
Output admittance (typ)	y_{oe}	0.08 + j0.82			mS	

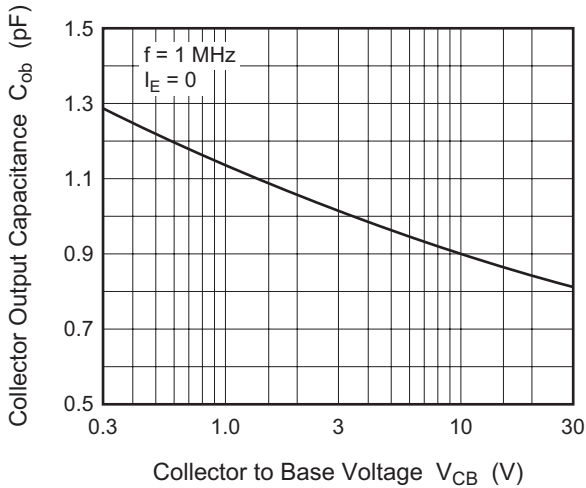
Note: 1. The 2SC535 is grouped by h_{FE} as follows.

B	C
60 to 120	100 to 200

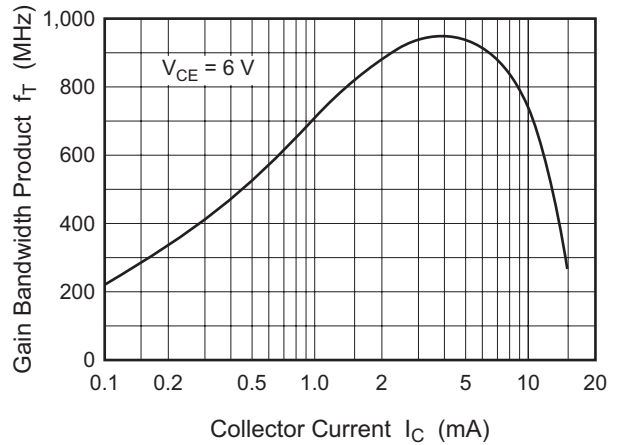
Main Characteristics



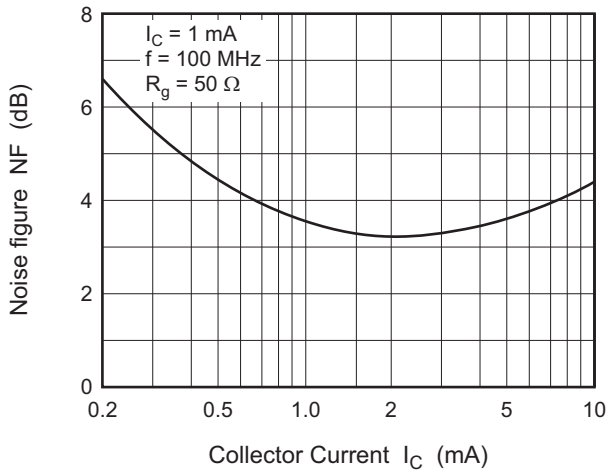
Collector Output Capacitance vs. Collector to Base Voltage



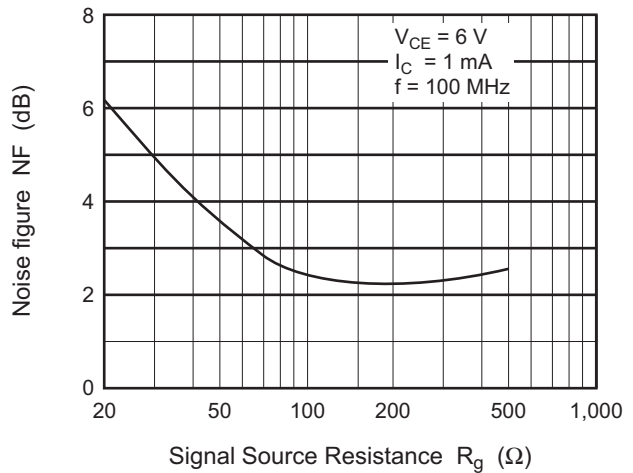
Gain Bandwidth Product vs. Collector Current



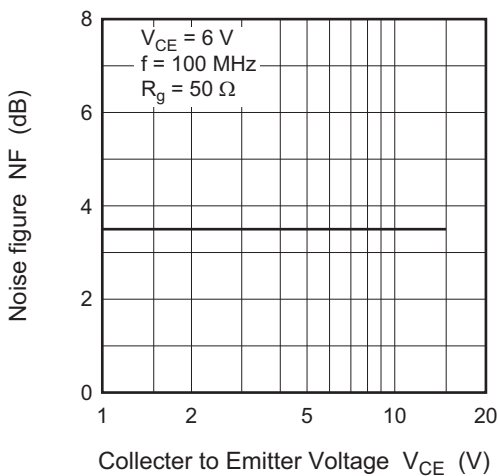
Noise Figure vs. Collector Current



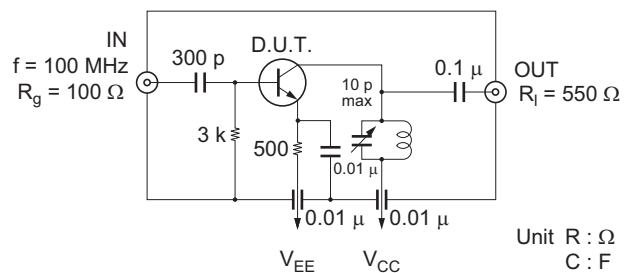
Noise Figure vs. Signal Source Resistance



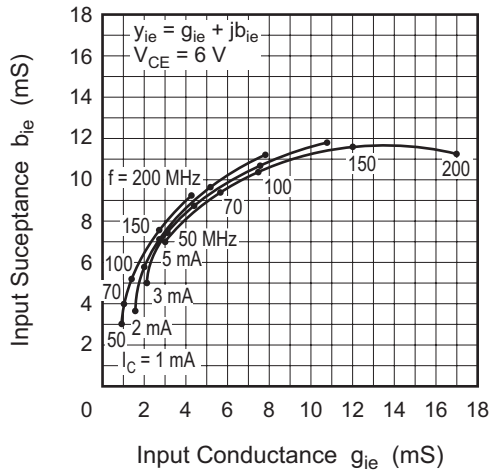
Noise Figure vs. Collector to Emitter Voltage



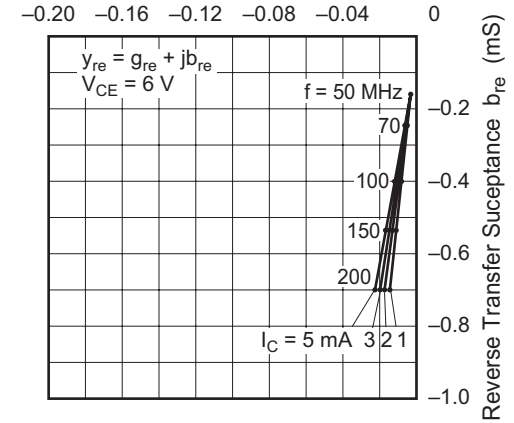
100 MHz Power Gain Test Circuit



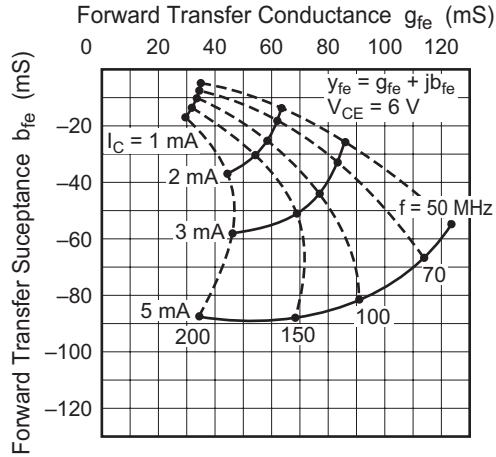
Input Admittance Characteristics



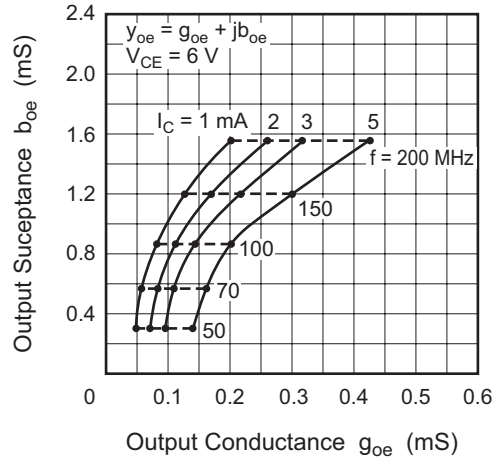
Reverse Transfer Admittance Characteristics



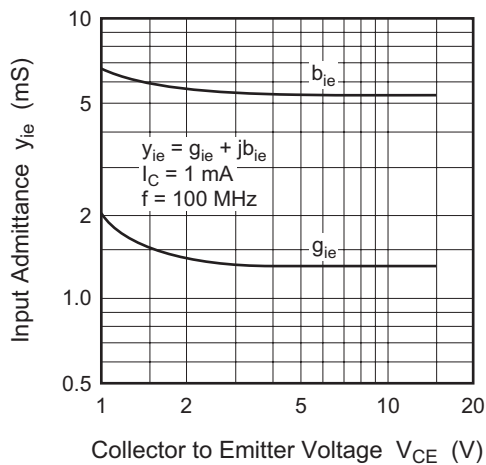
Forward Transfer Admittance Characteristics



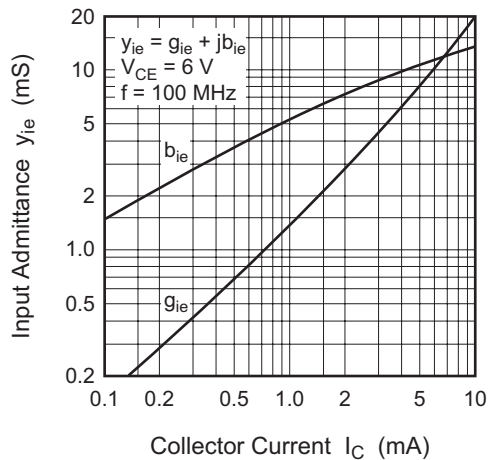
Output Admittance Characteristics

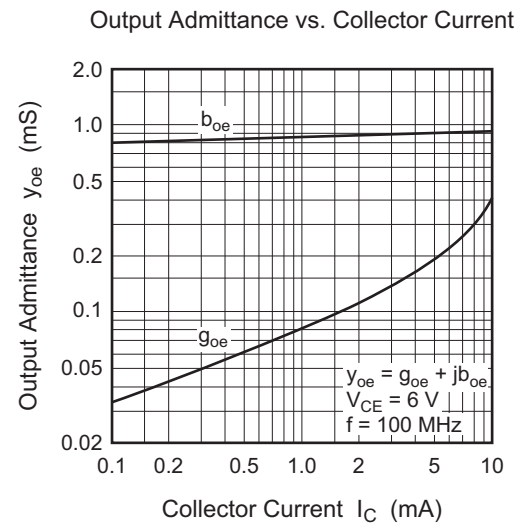
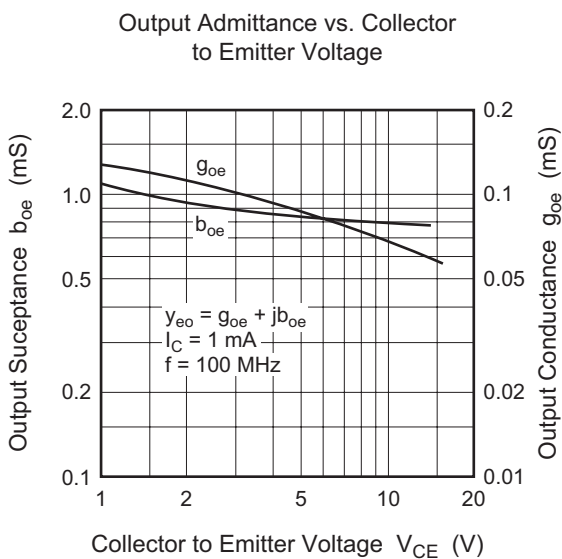
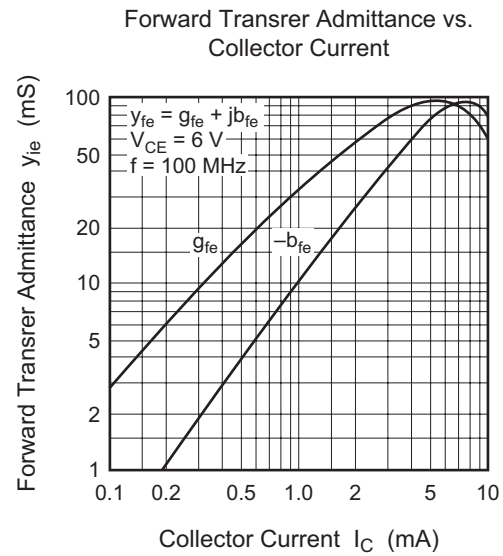
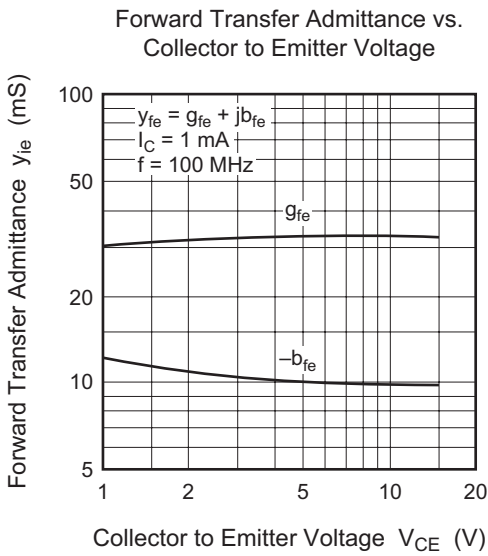
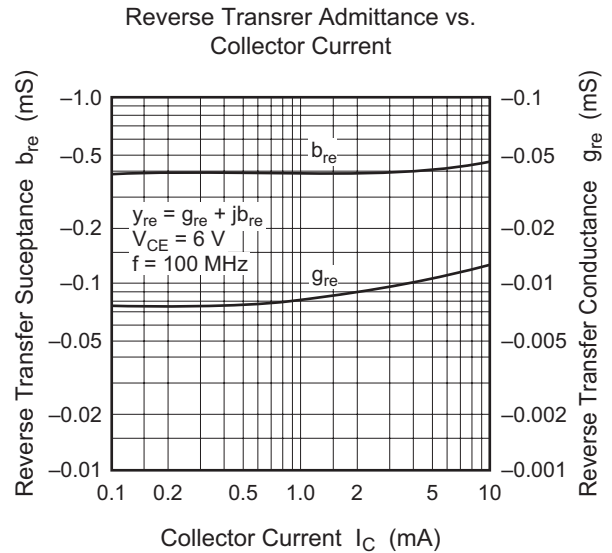
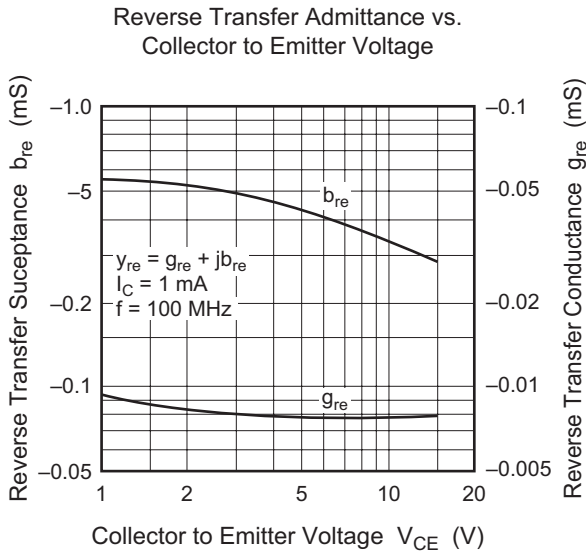


Input Admittance vs. Collector to Emitter Voltage

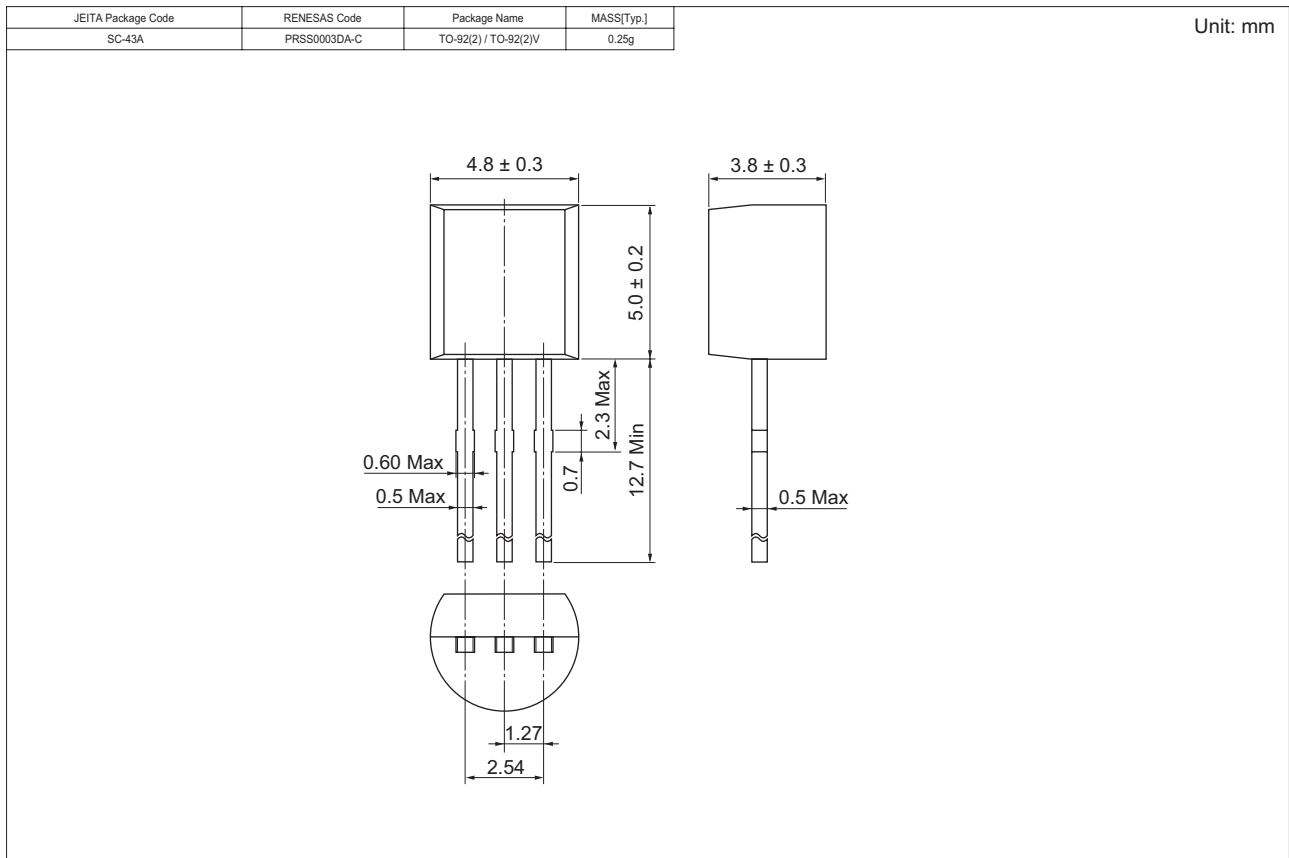


Input Admittance vs. Collector Current





Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
2SC535BTZ 2SC535CTZ	2500	Hold Box, Radial Taping

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